XUBLANCNM12

photo-electric sensor - XUB - thru beam - laser - Sn 100m - 12..24VDC - M12





Main

Range of product	OsiSense XU
Series name	Application material handling
Electronic sensor type	Photo-electric sensor
Sensor name	XUB
Sensor design	Cylindrical M18
Detection system	Thru beam
Material	Plastic
Type of output signal	Discrete
Supply circuit type	DC
Wiring technique	3-wire
Discrete output type	NPN
Discrete output function	1 NO or 1 NC programmable
Electrical connection	1 male connector M12
Emission	Red laser (class 1), wavelength: 670 nm conforming to IEC 825-1
[Sn] nominal sensing distance	100 m

Complementary

- Compression of		
Enclosure material	PBT	
Lens material	PMMA	
Blind zone	0 mm	
Output type	Solid state	
Status LED	1 LED (green) for supply on and teaching 1 LED (red) for stability 1 LED (yellow) for output state and alignment aid	
[Us] rated supply voltage	1224 V DC with reverse polarity protection	
Supply voltage limits	1030 V DC	
Switching capacity in mA	<= 100 mA (overload and short-circuit protection)	
Switching frequency	1500 Hz	
Voltage drop	<= 1.5 V (closed state)	
Current consumption	25 mA (no-load)	
Power consumption in W	< 1 W	
Delay first up	< 80 ms	
Delay response	< 0.4 ms	
Delay recovery	< 0.4 ms	
Setting-up	With sensitivity adjustment	
Product weight	0.078 kg	
Kit composition	Transmitter + receiver XUBLAKCNM12T + XUBLANCNM12R	

Environment

Product certifications	CE CSA UL
Ambient air temperature for operation	-1045 °C
Ambient air temperature for storage	-4070 °C
Vibration resistance	7 gn, amplitude = +/- 0.75 mm (f = 1055 Hz) conforming to IEC 60068-2-6
Shock resistance	30 gn (duration = 11 ms) conforming to IEC 60068-2-27
IP degree of protection	IP67 (double insulation) conforming to IEC 60529

Offer Sustainability

Sustainable offer status	Green Premium product
RoHS (date code: YYWW)	Compliant - since 0901 - Schneider Electric declaration of conformity
REACh	Reference not containing SVHC above the threshold

